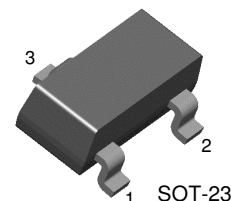


# BCX70J

BCX70J

## General Purpose Transistor



1. Base 2. Emitter 3. Collector

## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

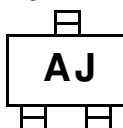
Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	45	V
$V_{CEO}$	Collector-Emitter Voltage	45	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current	200	mA
$P_C$	Collector Power Dissipation	350	mW
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

• Refer to KST3904 for graphs

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

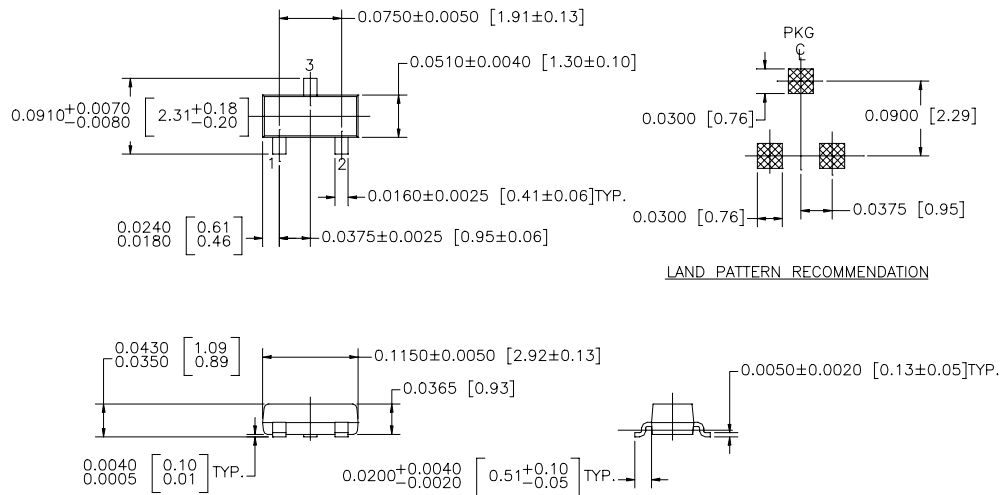
Symbol	Parameter	Test Condition	Min.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=2.0\text{mA}$ , $I_B=0$	45		V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=1.0\mu\text{A}$ , $I_C=0$	5		V
$I_{CES}$	Collector Cut-off Current	$V_{CE}=32\text{V}$ , $V_{BE}=0$		20	nA
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=4\text{V}$ , $I_C=0$		20	nA
$h_{FE}$	DC Current Gain	$V_{CE}=5\text{V}$ , $I_C=10\mu\text{A}$ $V_{CE}=5\text{V}$ , $I_C=2.0\text{mA}$ $V_{CE}=1\text{V}$ , $I_C=50\text{mA}$	40 250 90	460	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=10\text{mA}$ , $I_B=0.25\text{mA}$ $I_C=50\text{mA}$ , $I_B=1.25\text{mA}$		0.35 0.55	V V
$V_{BE}(\text{sat})$	Base-Emitter Saturation Voltage	$I_C=10\text{mA}$ , $I_B=0.25\text{mA}$ $I_C=50\text{mA}$ , $I_B=1.25\text{mA}$	0.6 0.7	0.85 1.05	V V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$I_C=2.0\text{mA}$ , $V_{CE}=5\text{V}$	0.55	0.75	V
$f_T$	Current Gain Bandwidth Product	$I_C=10\text{mA}$ , $V_{CE}=5\text{V}$ , $f=100\text{MHz}$	125		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10\text{V}$ , $I_E=0$ , $f=1\text{MHz}$		4.5	pF
NF	Noise Figure	$V_{CE}=5\text{V}$ , $I_C=0.2\text{mA}$ $R_S=2\text{K}\Omega$ , $f=1\text{KHz}$		6	dB
$t_{ON}$	Turn On Time	$I_C=10\text{mA}$ , $I_{B1}=1.0\text{mA}$		150	ns
$t_{OFF}$	Turn Off Time	$V_{BB}=3.6\text{V}$ , $I_{B2}=1.0\text{mA}$ $R_1=R_2=5\text{K}\Omega$ , $R_L=990\Omega$		800	ns

Marking



# Package Dimensions

## SOT-23



CONTROLLING DIMENSION IS INCH  
VALUES IN [ ] ARE MILLIMETERS

NOTE : UNLESS OTHERWISE SPECIFIED

1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS  
MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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Bottomless <sup>TM</sup>	FAST <sup>®</sup>	LittleFET <sup>TM</sup>	Power247 <sup>TM</sup>	SuperSOT <sup>TM</sup> -3
CoolFET <sup>TM</sup>	FAST <sup>r</sup> <sup>TM</sup>	MicroFET <sup>TM</sup>	PowerTrench <sup>®</sup>	SuperSOT <sup>TM</sup> -6
CROSSVOL <sup>TM</sup>	FRFET <sup>TM</sup>	MicroPak <sup>TM</sup>	QFET <sup>TM</sup>	SuperSOT <sup>TM</sup> -8
DOME <sup>TM</sup>	GlobalOptoisolator <sup>TM</sup>	MICROWIRE <sup>TM</sup>	QS <sup>TM</sup>	SyncFET <sup>TM</sup>
EcoSPARK <sup>TM</sup>	GTO <sup>TM</sup>	MSX <sup>TM</sup>	QT Optoelectronics <sup>TM</sup>	TinyLogic <sup>TM</sup>
E <sup>2</sup> CMOS <sup>TM</sup>	HiSeC <sup>TM</sup>	MSXPro <sup>TM</sup>	Quiet Series <sup>TM</sup>	TruTranslation <sup>TM</sup>
EnSigna <sup>TM</sup>	I <sup>2</sup> C <sup>TM</sup>	OCX <sup>TM</sup>	RapidConfigure <sup>TM</sup>	UHC <sup>TM</sup>
Across the board. Around the world. <sup>TM</sup>		OCXPro <sup>TM</sup>	RapidConnect <sup>TM</sup>	UltraFET <sup>®</sup>
The Power Franchise <sup>TM</sup>		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER <sup>®</sup>	VCX <sup>TM</sup>
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## PRODUCT STATUS DEFINITIONS

### Definition of Terms

Datasheet Identification	Product Status	Definition
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